



AH3563Q

Description

The AH3563Q is an AEC-Q100 qualified high-voltage, high-sensitivity Hall effect omnipolar switch IC designed for position and proximity sensing in automotive applications, such as in seat and seatbelt buckle, steering lock/immobilization, gear stick, transmission actuator and gear position, HVAC compression, wiper, door/trunk closure, and so on. To support a wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper-stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3563Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a zener clamp on the supply. The output has an overcurrent limit and a zener clamp.

The single open-drain output can be switched on with south or north pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (B_{OP}), the output is switched on (pulled low) and is held on until the magnetic flux density B is lower than the release point (B_{RP}).

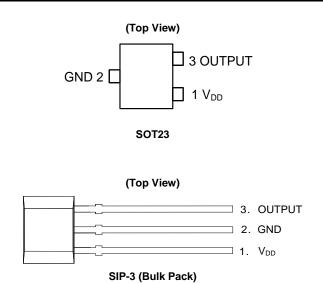
Features

- Omnipolar Operation
- High Sensitivity: BOP and BRP of ±30G and ±20G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV, CDM > 2kV
- Industry Standard SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AH3563Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

HIGH VOLTAGE HIGH SENSITIVITY AUTOMOTIVE HALL EFFECT OMNIPOLAR SWITCH

Pin Assignments



Applications

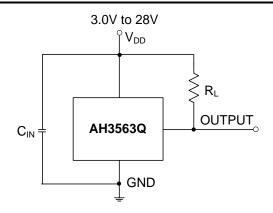
- · Position and Proximity Sensing in Automotive Applications
- · Open and Close Detect
- Position Detect
- Level Detect
- Flow Meters
- Contactless Switches
- Seatbelt Buckle
- Seat Position

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit

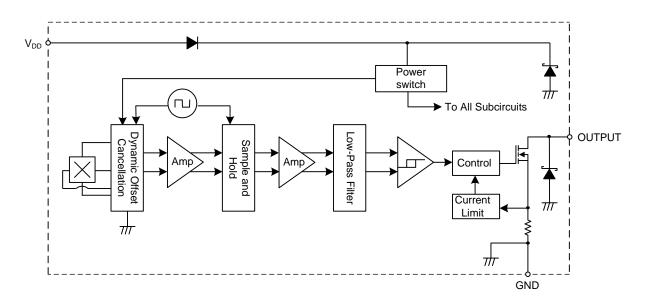


Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity; the recommended capacitance is 10nF ~ 100nF.

Pin Descriptions

Packages: SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)							
Pin Number	Pin Name	Function					
1	Vdd	Power Supply Input					
2	GND	Ground					
3	OUTPUT	Output Pin					

Functional Block Diagram





Absolute Maximum Ratings (Notes 5 and 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
Vdd	Supply Voltage (Note 6)		32	V	
Vddr	Reverse Supply Voltage (Note 6)	-32	V		
Vout_max	Output Off Voltage (Note 6)	t Off Voltage (Note 6)			
Іоит	Continuous Output Current	60	mA		
IOUT_R	Reverse Output Current	-50 mA			
В	Magnetic Flux Density		Unlimited	•	
PD	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW	
		SOT23	230	1	
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD HBM	Electros Static Discharge Withstand — Human Body Model	(HBM)	8	kV	
ESD MM	Electros Static Discharge Withstand — Machine Model (MM	1)	800	V	
ESD CDM	Electros Static Discharge Withstand — Charged Device Mo	del (CDM)	2	kV	

Notes: 5. Stresses greater than the 'Absolute Maximum Ratings' specified above can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

6. The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Condition	Rating	Unit
Vdd	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

Electrical Characteristics (Notes 7 and 8) (@T_A = -40°C to +150°C, V_{DD} = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vout_on	Output On Voltage	IOUT = 20mA, B > BOP	_	0.2	0.4	V
I _{LKG}	Output Leakage Current (When Output is Off)	Vout = 28V, B < B _{RP} , Output Off	—	0.1	10	μA
laa	Supply Current	Output Open, T _A = +25°C	—	3	3.5	mA
IDD	Supply Culterit	Output Open, T _A = -40°C to +150°C	—	_	4	mA
		V _{DD} = -18V, T _A = +25°C	—	0.6	—	μA
	Deverse Supply Current	V _{DD} = -18V, T _A = -40°C to +150°C	—	0.6	1500	μA
IDD_R	Reverse Supply Current	V _{DD} = -28V, T _A = +25°C	—	1.6	—	μA
		V _{DD} = -28V, T _A = -40°C to +150°C	—	1.6	2500	μA
tp_on	Device Power-On Time (Start-up Time)	$V_{DD} \ge 3V, B \ge B_{OP}$ (Note 7)	—	10	—	μs
fc	Chopping Frequency	—	—	800	—	kHz
t _D	Response Time Delay (Time from Magnetic Threshold Reached to the Start of the Output Rise or Fall)	(Note 9)	_	3.75	_	μs
tR	Output Rising Time (External Pull-up Resistor RL and Load Capacitance Dependent)	$R_L = 1k\Omega, C_L = 20pF$	_	0.2	1	μs
Output Falling Time tF (Internal Switch Resistance and Load Capacitance Dependent)		$R_L = 1k\Omega$, $C_L = 20pF$	_	0.1	1	μs
IOCL	Output Current Limit	B > B _{OP} (Note 10)	30	_	55	mA
Vz	Zener Clamp Voltage	I _{DD} = 5mA	28	_		V

Notes: 7. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

8. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control, and characterization.

9. Guaranteed by design, process control, and characterization. Not tested in production.

10. The device will limit the output current I_{OUT} to current limit of I_{OC}.

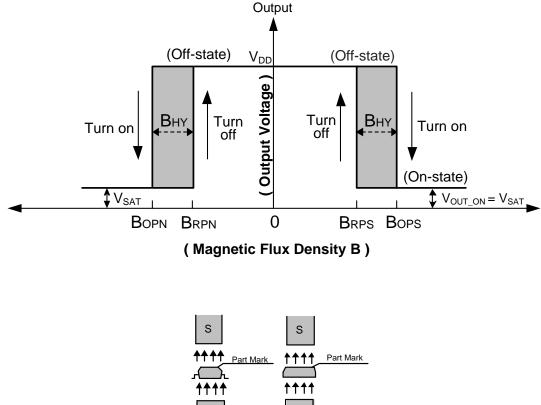


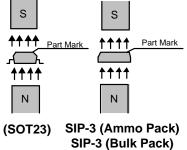
Magnetic Characteristics (Notes 11 and 12) (TA = -40°C to +150°C, VDD = 3.0V to 28V, unless otherwise specified.)

					(1mT =	10 Gauss)
Symbol	Parameter	Condition	Min	Тур	Max	Unit
B _{OPS} (South Pole to the Part Marking Side)		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	30		
BOPS (South Pole to the Part Marking Side)	Operation Point	T _A = -40°C to +150°C	15	30	45	
Denv (North Dolo to the Dort Marking Side)		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	-30	_	
PN (North Pole to the Part Marking Side)		$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	-45	-30	-15	
Para (South Polo to the Port Marking Side)		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	20	-	Gauss
BRPS (South Pole to the Part Marking Side)	Release Point	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	5	20	35	Causs
Provide Courth Date to the Dart Marking Cide)	Release Folli	$V_{DD} = 12V, T_A = +25^{\circ}C$	—	-20	-	
B _{RPN} (South Pole to the Part Marking Side)		T _A = -40°C to +150°C	-35	-20	-5	
	Hysteresis (Note 13)	$V_{DD} = 12V, T_A = +25^{\circ}C$	—	10	-	
Bhy (Bopx - Brpx)	Hysielesis (Note 13)	T _A = -40°C to +150°C	5	10	18	

11. When power is initially turned on, VDD must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid Notes: after the start-up time of 10µs typical from the operating voltage reaching 3V.

12. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization. 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.

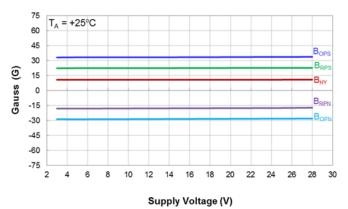




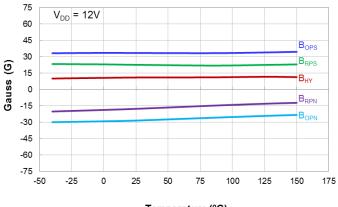


Typical Operating Characteristics

Output Switch Operate and Release Points (Magnetic Thresholds) - BOPS and BRPS



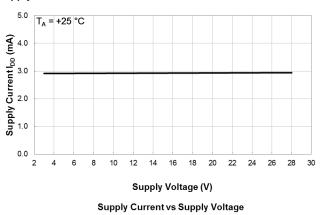
Switch Points BOPS and BRPS vs Supply Voltage

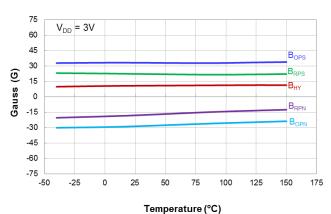


Temperature (°C)

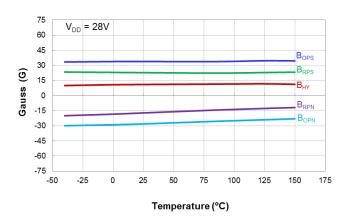
Switch Points B_{OPS} and B_{RPS} vs Temperature



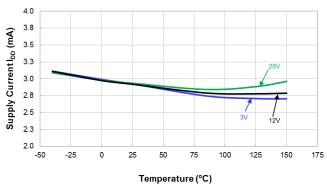




Switch Points B_{OPS} and B_{RPS} vs Temperature



Switch Points B_{OPS} and B_{RPS} vs Temperature

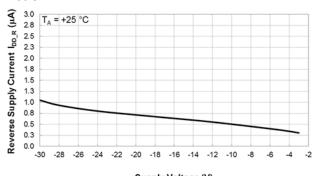


Supply Current vs Temperature

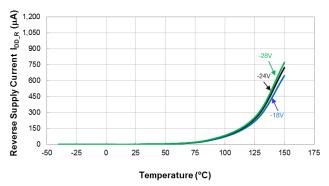


Typical Operating Characteristics (Continued)

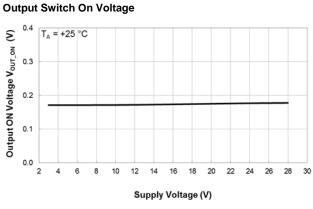
Supply Reverse Current



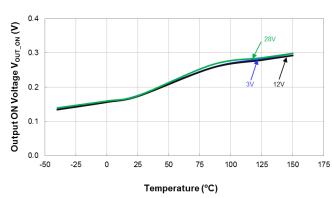
Supply Voltage (V) Reverse Supply Current vs Supply Voltage



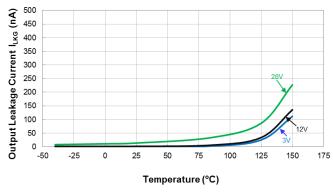
Reverse Supply Current vs Temperature



Output ON Voltage vs Supply Voltage

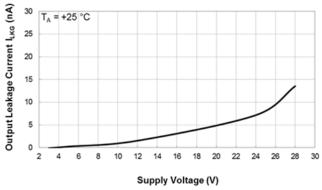






Output Leakage Current vs Temperature

Output Sv	witch L	eakage	Current
-			



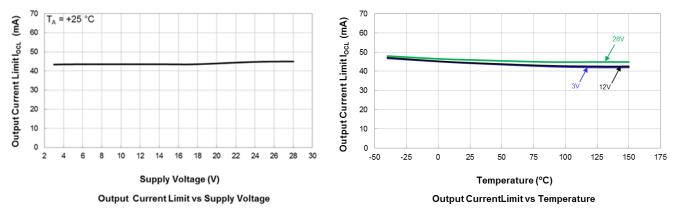
Output Leakage Current vs Supply Voltage



AH3563Q

Typical Operating Characteristics (Continued)

Output Current Limit

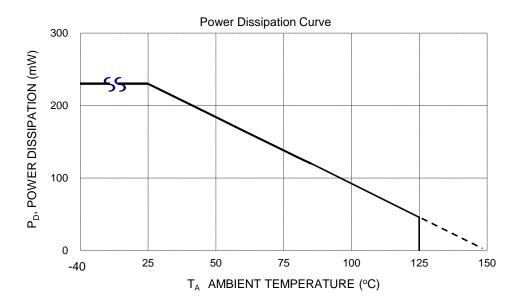




Thermal Performance Characteristics

(1) Package Type: SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0

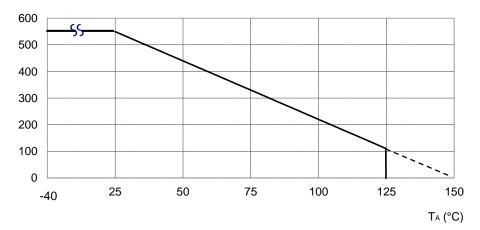


(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0

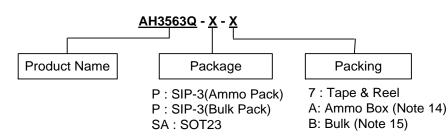


Power Dissipation Curve





Ordering Information

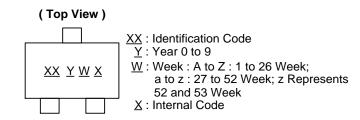


			B	Bulk	Ammo	Box	7" Tape and Reel		
Part Number	Package Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix	
AH3563Q-P-A	Р	SIP-3 (Ammo Pack)	NA	NA	4,000/Box	-A	NA	NA	
AH3563Q-P-B	Р	SIP-3 (Bulk Pack)	1000	-B	NA	NA	NA	NA	
AH3563Q-SA-7	SA	SOT23	NA	NA	NA	NA	3,000/Tape & Reel	-7	

Notes: 14. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead. 15. Bulk is for SIP-3 (Bulk Pack) Straight Lead.

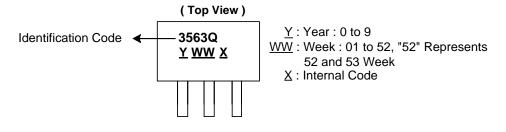
Marking Information

(1) Package Type: SOT23



Part Number	Package	Identification Code
AH3563Q-SA-7	SOT23	Z3

(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)



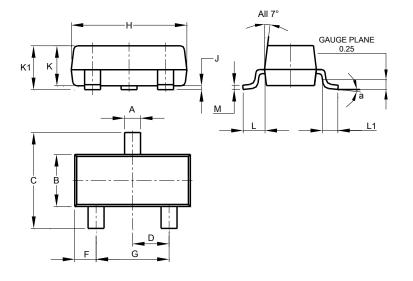
Part Number	Package	Identification Code		
AH3563Q-P-A	SIP-3 (Ammo Pack)	3563Q		
AH3563Q-P-B	SIP-3 (Bulk Pack)	3563Q		



Package Outline Dimensions (All dimensions in mm.)

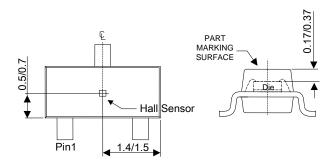
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
К	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	_
All	Dimens	ions in	mm

Min/Max



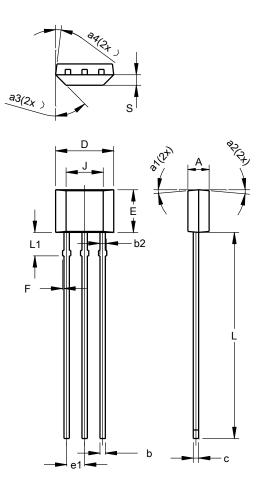
Sensor Location



Package Outline Dimensions (Continued) (All dimensions in mm.)

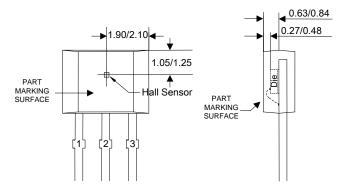
Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SIP-3 (Bulk Pack)



SIP-3 (Bulk Pack)				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
b	0.33	0.43	0.38	
b2	0.40	0.508	0.46	
С	0.35	0.41	0.38	
D	3.90	4.30	4.10	
E	2.80	3.20	3.00	
e1	1.24	1.30	1.27	
F	0.00	0.20		
J	2.62 REF			
L	14.00	15.00	14.50	
L1	1.55	1.75	1.65	
s	0.63	0.84	0.74	
a1			5°	
a2			5°	
a3			45°	
a4			3°	
All Dimensions in mm				

Min/Max



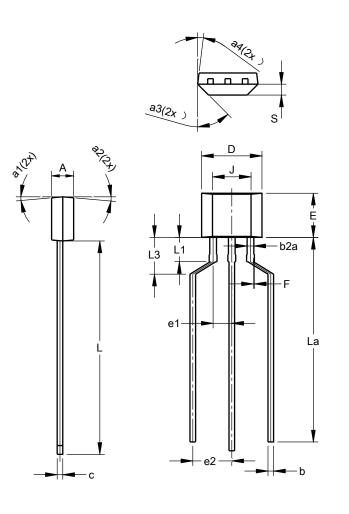
Sensor Location



Package Outline Dimensions (Continued) (All dimensions in mm.)

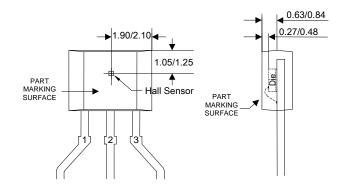
Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: SIP-3 (Ammo Pack)



1	SIE	1.2		
SIP-3 (Ammo Pack)				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
b	0.33	0.43	0.38	
b2a	0.40	0.52	0.46	
C	0.35	0.41	0.38	
D	3.90	4.30	4.10	
E	2.80	3.20	3.00	
e1	1.24	1.30	1.27	
e2	2.40	2.90	2.65	
F	0.00	0.20	—	
J	2.62 REF			
L	14.00	15.00	14.50	
La	12.90	14.90	13.90	
L1	1.55	1.75	1.65	
L3	2.00	3.00	2.50	
S	0.63	0.84	0.74	
a1	_	_	5°	
a2	_		5°	
a3	_		45°	
a4	_		3°	
All Dimensions in mm				

Min/Max



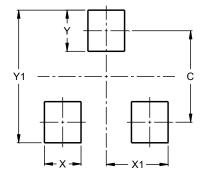
Sensor Location



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

Mechanical Data

SOT23 Package

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.009 grams (Approximate)

SIP-3 (Bulk Pack), SIP-3 (Ammo Pack) Packages

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.12 grams (Approximate)



IMPORTANT NOTICE

1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

products provided Diodes' Standard and Conditions Sale 5 Diodes subject to Terms of are (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2020 Diodes Incorporated

www.diodes.com